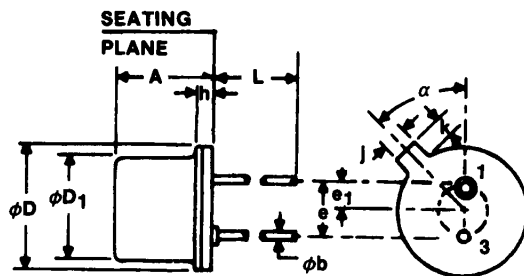




GaAs INFRARED EMITTING DIODE

CQX15, CQX17

PACKAGE DIMENSIONS



ST1331

SYMBOL	INCHES		MILLIMETERS		NOTES
	MIN.	MAX.	MIN.	MAX.	
A		.155		3.93	
⊙b	.016	.021	.407	.533	
⊙D	.209	.230	5.31	5.84	
⊙D1	.180	.187	4.57	4.77	
e	.100 NOM.		2.54 NOM.		2
e1	.050 NOM.		1.27 NOM.		2
h		.030		.76	
j	.031	.044	.79	1.11	
k	.036	.046	.92	1.16	1
L	1.00		25.4		
α	45°	45°	45°	45°	3

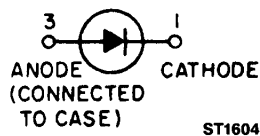
DESCRIPTION

The CQX15/17 are 940nm LEDs in wide angle, TO-46 packages.

FEATURES

- Good optical to mechanical alignment
- Mechanically and wavelength matched to TO-18 phototransistor
- Hermetically sealed package
- High irradiance level
- European "Pro Electron" registered

PACKAGE OUTLINE



NOTES:

1. MEASURED FROM MAXIMUM DIAMETER OF DEVICE.
2. LEADS HAVING MAXIMUM DIAMETER .021" (.533mm) MEASURED IN GAUGING PLANE .054" + .001" - .000 (137 + 025 - 000mm) BELOW THE REFERENCE PLANE OF THE DEVICE SHALL BE WITHIN .007" (.778mm) THEIR TRUE POSITION RELATIVE TO MAXIMUM WIDTH TAB.
3. FROM CENTERLINE TAB.



GaAs INFRARED EMITTING DIODE

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ Unless Otherwise Specified)	
Storage Temperature	-65°C to +150°C
Operating Temperature	-65°C to +125°C
Soldering:	
Lead Temperature (Iron)	240°C for 5 sec. ^(3,4,5,6)
Lead Temperature (Flow)	260°C for 10 sec. ^(3,4,6)
Continuous Forward Current	100 mA
Forward Current (pw, 1 μS ; 200 Hz)	10 A
Reverse Voltage	3 Volts
Power Dissipation ($T_A = 25^\circ\text{C}$)	170 mW ⁽¹⁾
Power Dissipation ($T_C = 25^\circ\text{C}$)	1.3 W ⁽²⁾

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ Unless Otherwise Specified) (All measurements made under pulse conditions.)						
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNITS	TEST CONDITIONS
Forward Voltage	V_F	—		1.7	V	$I_F = 100 \text{ mA}$
Reverse Leakage Current	I_R	—		10	μA	$V_R = 3 \text{ V}$
Peak Emission Wavelength	λ_P		940		nm	$I_F = 100 \text{ mA}$
Emission Angle at 1/2 Power	θ		± 40		Degrees	
Total Power CQX15	P_O	5.4		—	mW	$I_F = 100 \text{ mA}^{(7)}$
Total Power CQX17	P_O	1.5		—	mW	$I_F = 100 \text{ mA}^{(7)}$
Rise Time 0-90% of output	t_r		1.0		μS	
Fall Time 100-10% of output	t_f		1.0		μS	

NOTES
1. Derate power dissipation linearly 1.70mW/°C above 25°C ambient.
2. Derate power dissipation linearly 13.0mW/°C above 25°C case.
3. RMA flux is recommended.
4. Methanol or Isopropanol alcohols are recommended as cleaning agents.
5. Soldering iron tip 1/16" (1.6 mm) minimum from housing.
6. As long as leads are not under any stress or spring tension.
7. Total power output, P_O , is the total power radiated by the device into a solid angle of 2π steradians.

